

High voltage fast-switching NPN power transistor

Preliminary data

Features

- High voltage capability
- Low spread of dynamic parameters
- Minimum lot-to-lot spread for reliable operation
- Very high switching speed
- Integrated antiparallel collector-emitter diode

Applications

- Electronic ballast for fluorescent lighting
- Electronic transformer for halogen lamps

Description

This device is an NPN power transistor manufactured using high voltage multi epitaxial planar technology for high switching speeds. It uses a cellular emitter structure with planar edge termination to enhance switching speeds while maintaining a satisfactory RBSOA.

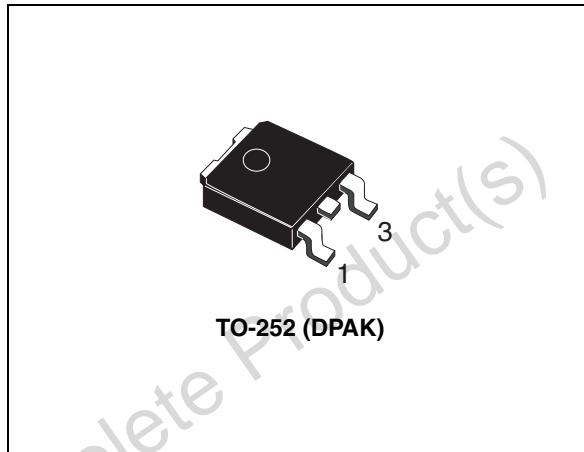


Figure 1. Internal schematic diagram

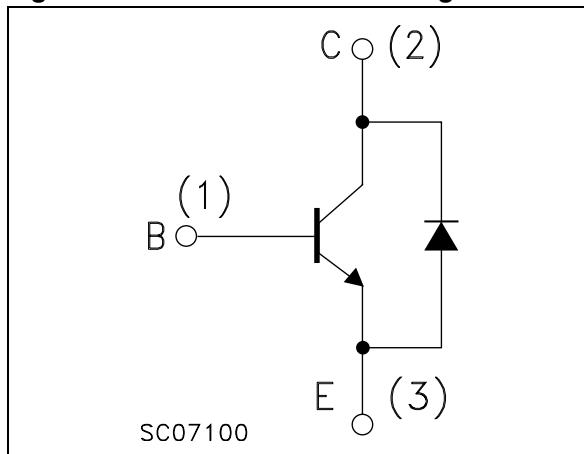


Table 1. Device summary

Part number	Marking	Package	Packaging
TRD236DT4	TRD236D	TO-252	Tape and reel

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1 Electrical ratings

Table 2. Absolute maximum rating

Symbol	Parameter	Value	Unit
V_{CES}	Collector-emitter voltage ($V_{BE} = 0$)	700	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	400	V
V_{EBO}	Emitter-base voltage ($I_C = 0$, $I_B = 2$ A, $t_p < 10 \mu s$)	$V_{(BR)EBO}$	V
I_C	Collector current ($I_C = 0$)	4	A
I_{CM}	Collector peak current ($t_p < 5$ ms)	8	A
I_B	Base current	2	A
I_{BM}	Base peak current ($t_p < 5$ ms)	4	A
P_{tot}	Total dissipation at $T_c \leq 25$ °C	35	W
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

2 Electrical characteristics

($T_{case} = 25^\circ C$ unless otherwise specified)

Table 3. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{CES}	Collector cut-off current ($V_{BE} = 0$)	$V_{CE} = 700 V$ $V_{CE} = 700 V \quad T_C = 125^\circ C$			0.1 0.5	mA mA
I_{CEO}	Collector cut-off current ($I_B = 0$)	$V_{CE} = 400 V$			0.25	mA
$V_{(BR)EBO}$	Emitter-base breakdown voltage ($I_C = 0$)	$I_E = 10 mA$	9		18	V
$V_{CEO(sus)}^{(1)}$	Collector-emitter sustaining voltage ($I_B = 0$)	$I_C = 10 mA$	400			V
$V_{CE(sat)}^{(1)}$	Collector-emitter saturation voltage	$I_C = 0.8 A \quad I_B = 0.1 A$ $I_C = 2.5 A \quad I_B = 0.6 A$			1.1 1.3	V V
$V_{BE(sat)}^{(1)}$	Base-emitter saturation voltage	$I_C = 1 A \quad I_B = 0.2 A$ $I_C = 2.5 A \quad I_B = 0.5 A$			1.2 1.3	V V
h_{FE}	DC current gain	$I_C = 10 mA \quad V_{CE} = 5 V$ $I_C = 2.5 A \quad V_{CE} = 5 V$	10 8		28	
t_s t_f	Inductive load Storage time Fall time	$V_{CC} = 200 V \quad I_C = 2 A$ $I_{B1} = 0.4 A \quad V_{BE(off)} = -5 V$ $R_{BB} = 0 \Omega \quad L = 200 \mu H$ (see Figure 13)		0.6 0.1		μs μs
V_F	Diode forward voltage	$I_F = 2 A$			2.5	V

1. Pulsed duration = 300 ms, duty cycle $\leq 1.5\%$

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

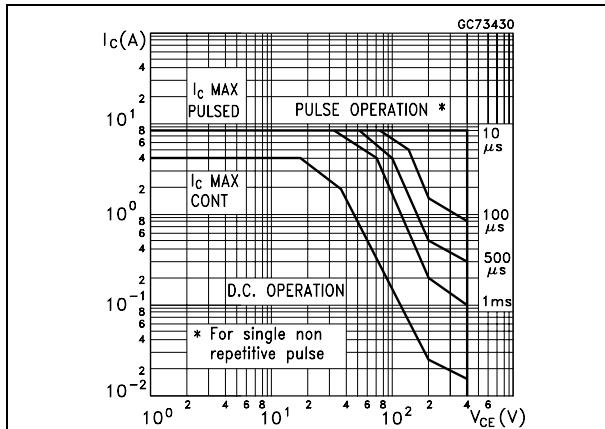


Figure 3. Derating curve

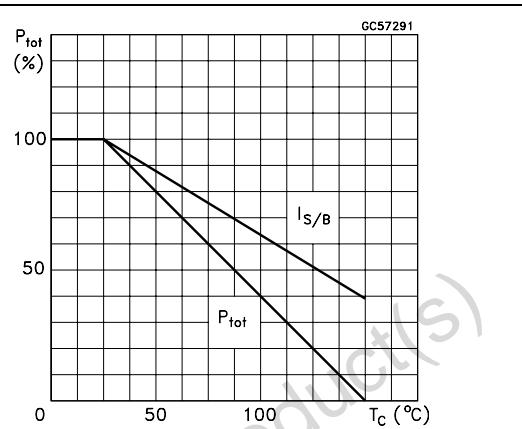


Figure 4. DC current gain ($V_{CE} = 1.5$ V)

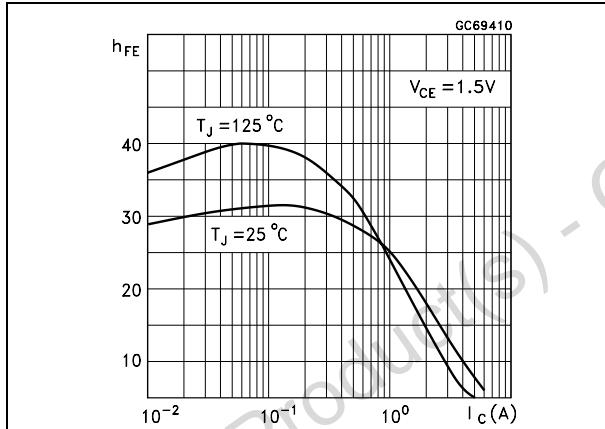


Figure 5. DC current gain ($V_{CE} = 5$ V)

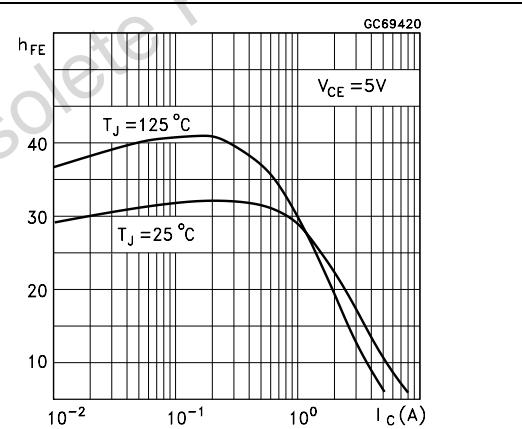


Figure 6. Collector-emitter saturation voltage **Figure 7. Base-emitter saturation voltage**

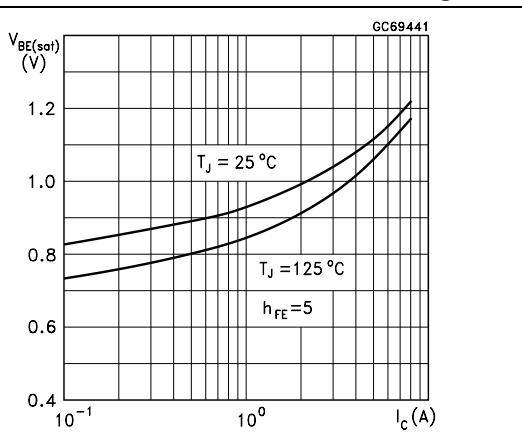
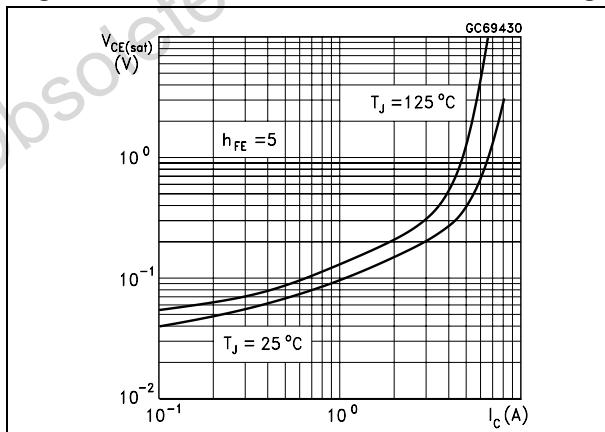
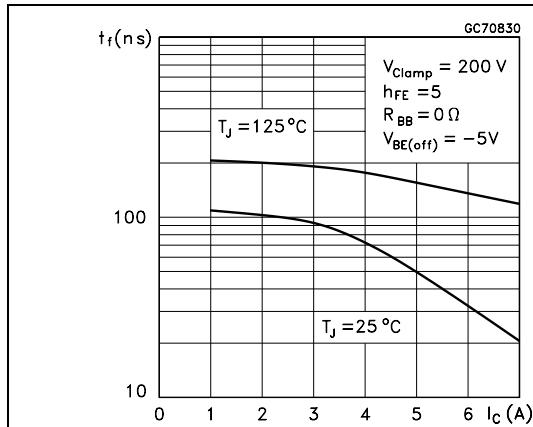
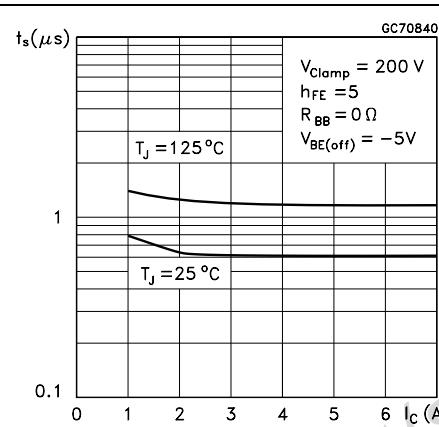
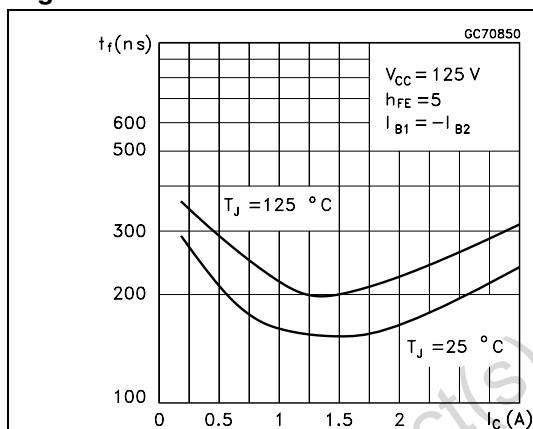
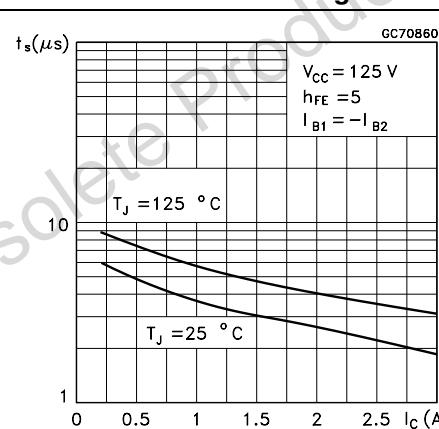
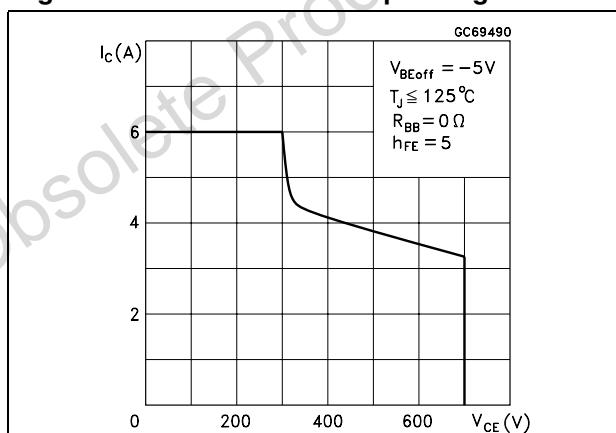
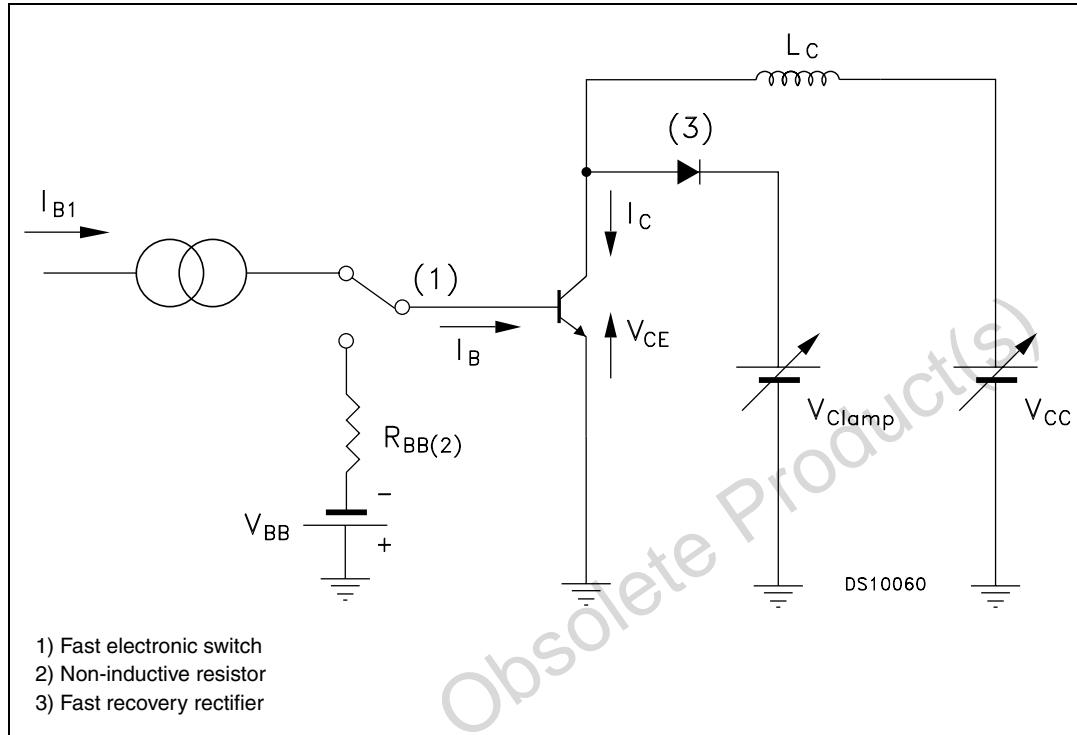


Figure 8. Inductive load fall time**Figure 9. Inductive load storage time****Figure 10. Resistive load fall time****Figure 11. Resistive load storage time****Figure 12. Reverse biased operating area**

2.2 Test circuits

Figure 13. Inductive load switching test circuit



3 Package mechanical data

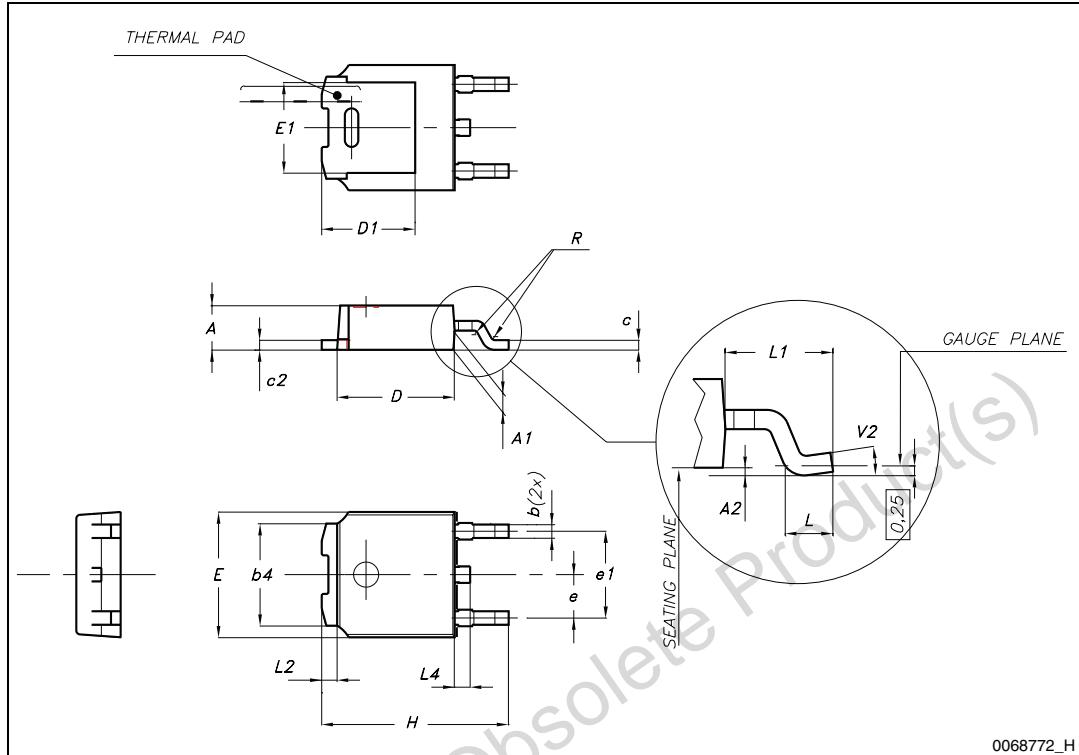
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Table 4. DPAK (TO-252) mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
c	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
e		2.28	
e1	4.40		4.60
H	9.35		10.10
L	1		1.50
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0°		8°

Figure 14. DPAK (TO-252) drawing



4 Revision history

Table 5. Document revision history

Date	Revision	Changes
28-Jun-2011	1	First release

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